



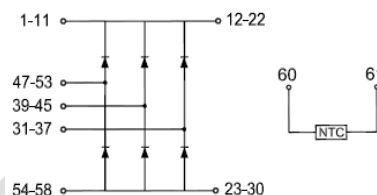
RD900FF180T6HJ

Rectifier Diode Module

Preliminary Data

Features:

- Blocking Voltage:1800V
- Heat Transfer Through Aluminum Oxide DBC Ceramic Isolated Metal Baseplate
- Double-Sided Silver Chip
- Three Phase Bridge Rectifier



Applications:

- Non-Controllable Rectifiers for AC/AC Converters
- Line Rectifiers for Transistorized AC Motor Controllers
- Field Supply for DC Motors
- Three Phase Rectifiers for Power Supplies

Maximum Rated Values

Symbol	Description	Conditions	Min.	Typ.	Max.	Units
V_{RRM}	Repetitive Peak Reverse Voltage	$T_j = 25^{\circ}\text{C}$, $I_{RRM} = 5\text{uA}$	1800			V
Internal Isolation			Al ₂ O ₃			
I_{FAV}	Average Forward Current	$T_j = 25^{\circ}\text{C}$, $T_s = 80^{\circ}\text{C}$			900	A
I_{FSM}	Surge Current @ $t_p = 10\text{ ms}$	$t_p = 10\text{ms}$, $\sin 180^{\circ}$, $T_j = 25^{\circ}\text{C}$			10.08	kA
i^2t	I^2t - value	$t_p = 10\text{ms}$, $\sin 180^{\circ}$, $T_j = 25^{\circ}\text{C}$			508	kA ² s
P_D	Maximum Power Dissipation per Diode	$T_c = 25^{\circ}\text{C}$ $T_{Jmax} = 150^{\circ}\text{C}$		1560		W
V_{iso}	Isolation Voltage(All Terminals Shorted)	AC 50Hz;r.m.s.;1min	3000			V
T_{vj}	Maximum Operating Junction Temperature Range		-40		150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature		-40		125	$^{\circ}\text{C}$
T	Mounting Screw:M5		3.0		6.0	Nm
G	Weight			300		g



Thermal Characteristics

Symbol	Description	Min.	Typ.	Max.	Unit
$R_{th(j-c)}$	Diode Thermal Resistance: Junction-To-Case		0.08		$^{\circ}\text{C}/\text{W}$
$R_{th(c-s)}$	Case-To-Sink Thermally (Conductive Grease Applied)		0.02		$^{\circ}\text{C}/\text{W}$

Electrical Characteristics

Symbol	Description	Conditions	Values			Unit
			Min	Typ	Max	
V_F	Forward Voltage	$I_F=300\text{A}, T_J=25^{\circ}\text{C}$		1.10		V
		$I_F=900\text{A}, T_J=25^{\circ}\text{C}$		1.30		
		$I_F=300\text{A}, T_J=125^{\circ}\text{C}$		1.00		V
		$I_F=900\text{A}, T_J=125^{\circ}\text{C}$		1.30		
I_R	Reverse Current	$V_{RD}=1800\text{V}, T_J=25^{\circ}\text{C}$		15	1000	μA
		$V_{RD}=1800\text{V}, T_J=125^{\circ}\text{C}$			5	mA

Internal NTC-Thermistor Characteristics

Symbol	Description		Min.	Typ.	Max.	Units.
R_{25}	Rated Resistance	$T_C=25^{\circ}\text{C}$		5		k Ω
$\Delta R/R$	Deviation of R100	$T_C=100^{\circ}\text{C}, R_{100}=481\Omega$	-5		5	%
P_{25}	Power Dissipation	$T_C=25^{\circ}\text{C}$			10	mW
$B_{25/50}$	B-Value	$R_2=R_{25} \exp[B_{25/50}(1/T_2-1/(298.15\text{K}))]$		3380		K
$B_{25/80}$	B-Value	$R_2=R_{25} \exp[B_{25/80}(1/T_2-1/(298.15\text{K}))]$		3440		K

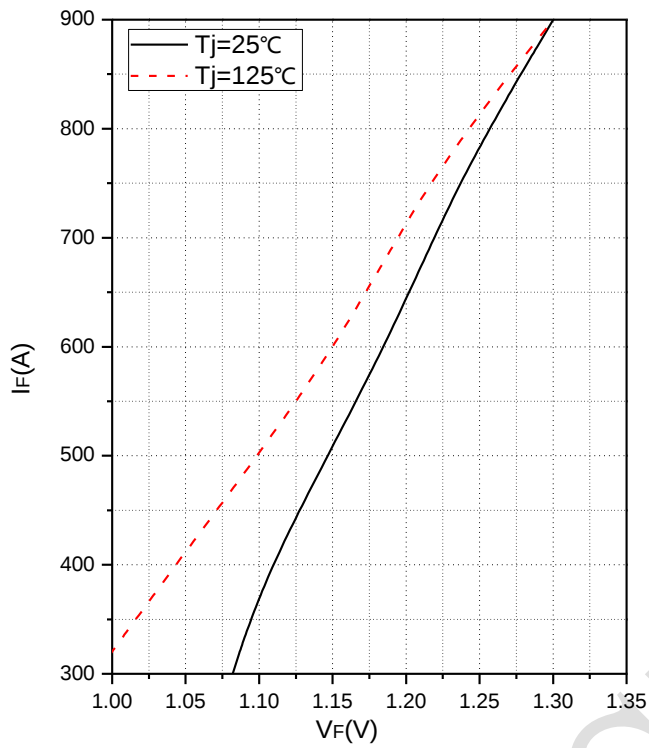


Fig.1 Forward Characteristics

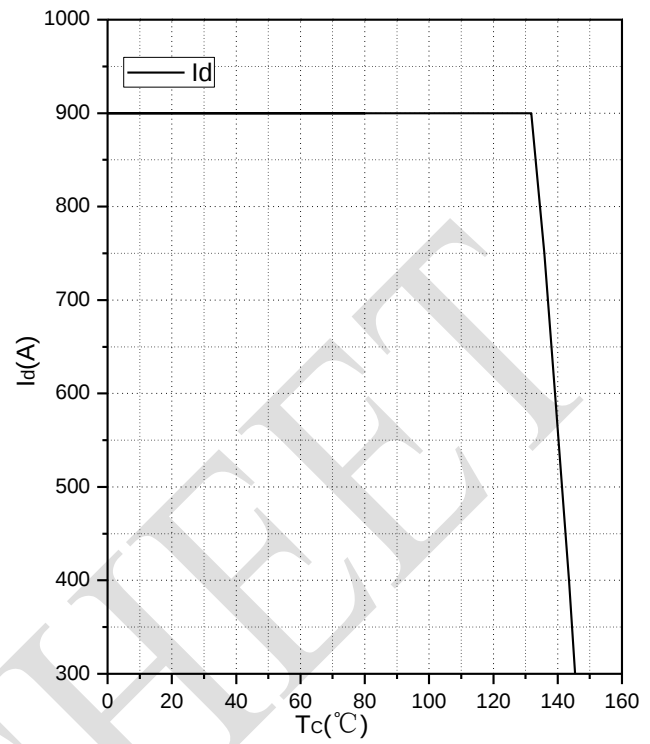


Fig.2 Forward Current Derating Curve

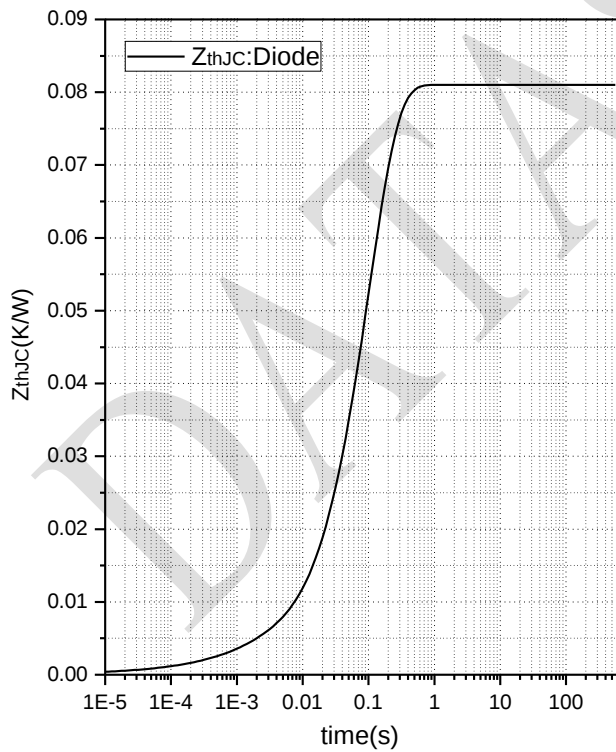


Fig.3 Transient Thermal Impedance

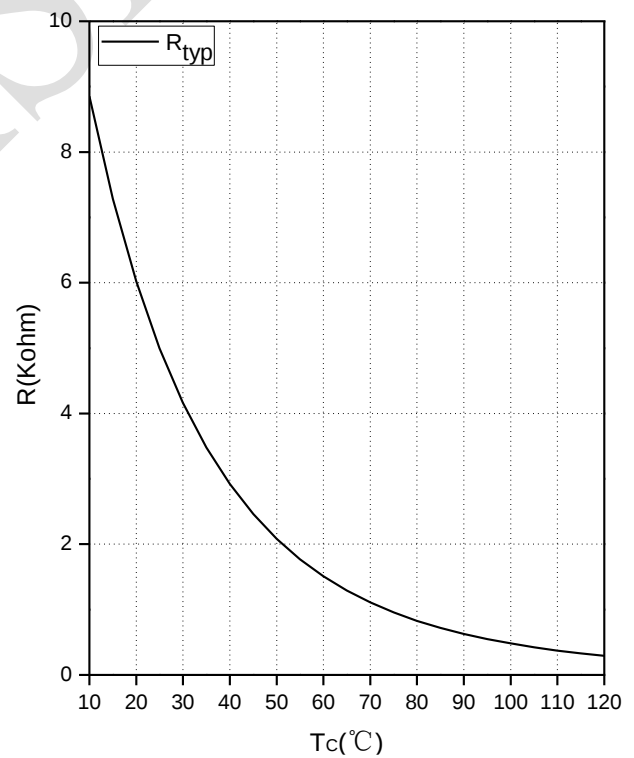
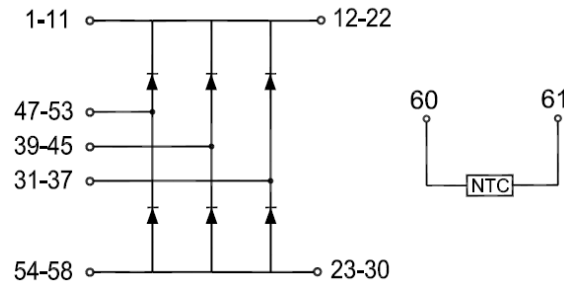


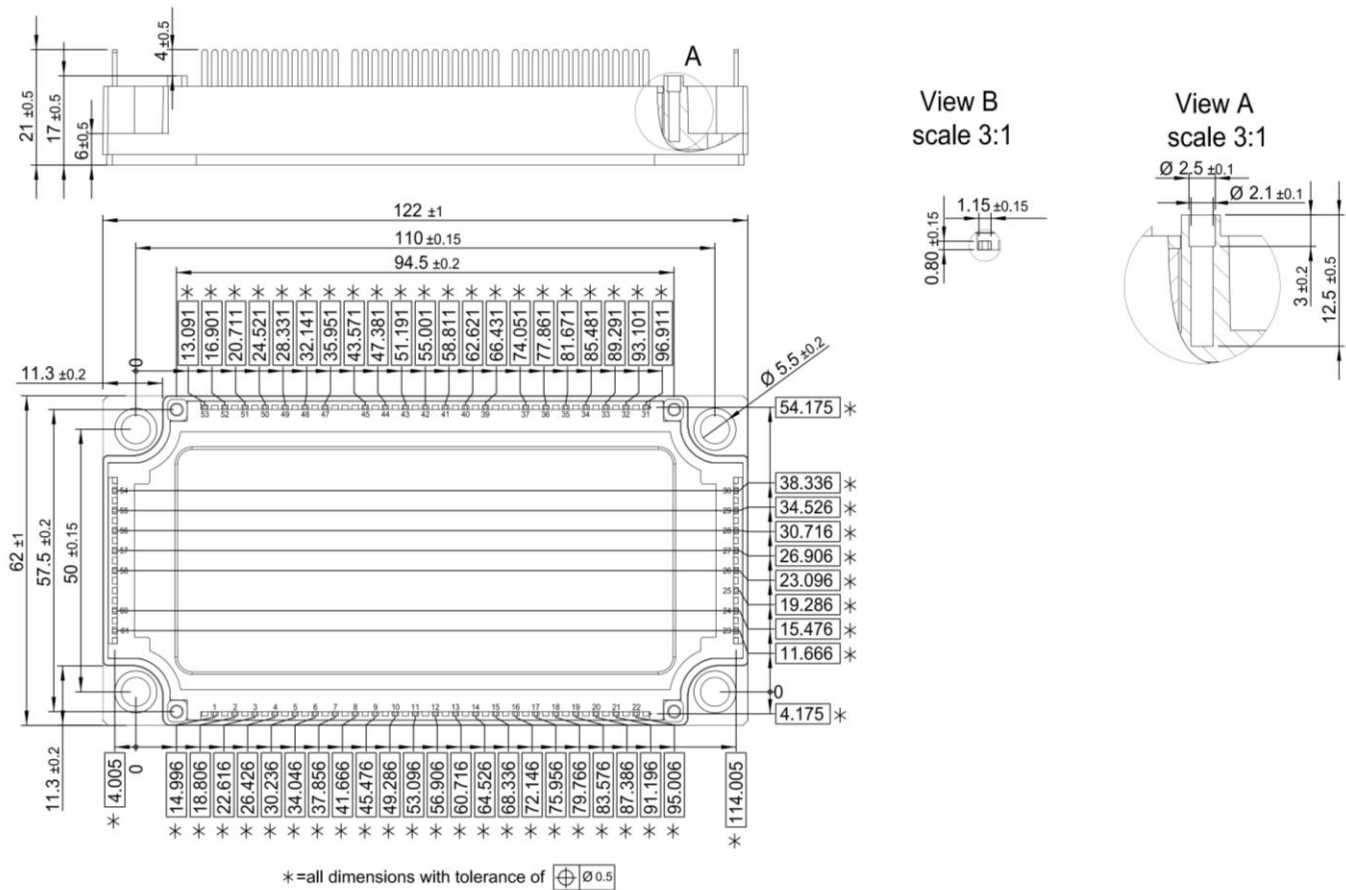
Fig.4 NTC Temperature Characteristics



Internal Circuit



Package Outline Information (Unit: mm):





Date	Revision	Notes
12/31/2019	01	Initial release

Announcement

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